	Type	L#	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	6020		USPAT; USOCR	2005/05/30 19:36
2	BRS	L2	2178	l and (tft (thin adj film adj transistor))	USPAT	2005/05/30 19:36
3	BRS	L3	11 21) /	2 and (soi ((insulated insulating insulation) near3 substrate))	USPAT	2005/05/30 19:37
4	BRS	L4	394	3 and (capacitor (auxiliary adj capacitor))	USPAT	2005/05/30 19:37
5	BRS	L5	269	4 and pixel adj electrode	USPAT	2005/05/30 19:38
6	BRS	L6	253	5 and @ad<"20030331"	USPAT	2005/05/30 19:38
7	BRS	L7	103	6 and (pixel adj electrode) near5 ((contact adj hole) via (through adj hole) opening hole holes aperture apertures)	USPAT	2005/05/30 19:40